

**WW5906, WW5907,
WW5980 thru WW6005
Silicon Power Rectifier Diode, 40Amp**

Features:

- High Surge Current Capability
- High Voltage Available
- Designed for a Wide Range of Applications
- Available in Anode-to-Case or Cathode-to-Case Style

Ratings and Characteristics:

Average Forward Current ($T_C = +140^\circ\text{C}$ Max), $I_{F(AV)}$	40A
Maximum Forward Surge Current, I_{FSM}	
50Hz	480A
60Hz	500A
Fusing Current, I^2t	
50Hz	1150A ² s
60Hz	1050A ² s
Fusing Current, $I^2\sqrt{t}$	16000A ² \sqrt{s}
Maximum Reverse Recovery Voltage Range, V_{RRM}	50 to 1600V

Voltage Ratings:

Cathode to Case	Anode to Case	V_{RRM} -Max Repetitive Peak Reverse Volt. (V)	V_{RSM} -Max Non-Repetitive Peak Reverse Voltage (V) $t_p < 5\text{ms}$	V_R -Max. Direct Reverse Voltage (V)	$V_{R(SR)}$ Minimum Avalanche Voltage (V)	I_{RM} -Max Reverse Current Rated V_{RRM} (mA)
		$T_J = -65^\circ \text{ to } +150^\circ\text{C}$	$T_J = +25^\circ \text{ to } +150^\circ\text{C}$	$T_J = -65^\circ \text{ to } +150^\circ\text{C}$	$T_J = +25^\circ\text{C}$	$T_J = +150^\circ\text{C}$
5980	5981	50	100	50	—	15
5982	5983	100	200	100	—	15
5986	5987	200	300	200	—	15
5988	5989	300	450	300	—	15
5990	5991	400	500	400	500	15
5992	5993	500	600	500	600	9
5994	5995	600	720	600	725	9
5998	5999	800	960	800	960	9
6002	6003	1000	1200	1000	1150	9
5906	5907	1200	1400	1200	1350	9
6004	6005	1600	1700	1600	1700	9



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Electrical Specifications:

Parameter	Symbol	Test Conditions		Rating	Unit
Maximum Average Forward Current	$I_F (AV)$	180° sinusoidal condition, $T_C = +140^{\circ}\text{C}$ Max		40	A
Maximum Peak One–Cycle Non–Repetitive Surge Current	I_{FSM}	Half cycle 50Hz sine wave or 8ms rectangular pulse	Following any rated load condition and with rated V_{RRM} applied	480	A
		Half cycle 60Hz sine wave at 5ms rectangular pulse		500	A
		Half cycle 50Hz sine wave or 6ms rectangular pulse	Following any rated load condition and with V_{RRM} applied following surge = 0	570	A
		Half cycle 60Hz sine wave at 3ms rectangular pulse		586	A
Maximum I^2t for Fusing	I^2t	t = 10ms	With rated V_{RRM} ap- plied following surge	1150	A^2s
		t = 8.3ms		1050	A^2s
Maximum I^2t for Individual Device Fusing		t = 10ms	With $V_{RRM} = 0$ fol- lowing surge	1600	A^2s
		t = 8.3ms		1450	A^2s
Maximum $I^2\sqrt{t}$	$I^2\sqrt{t}$	t = 0.1 to 10ms, $V_{RRM} = 0$ following surge		16000	$\text{A}^2\sqrt{t}$
Maximum Peak Forward Voltage	V_{FM}	$I_F (AV) = 40\text{A}$ (125 peak), $T_J = +25^{\circ}\text{C}$		1.30	V
Maximum Value of Threshold Voltage	$V_M (TO)$	$T_J = +100^{\circ}\text{C}$		0.69	V
Maximum Value of Forward Slope Resistance	r_t	$T_J = +100^{\circ}\text{C}$		3.79	mΩ

Thermal-Mechanical Specifications:

Parameter	Symbol	Test Conditions	Rating	Unit
Maximum Operation Junction Temperature	T_J		-65 to + 190	$^\circ\text{C}$
Maximum Storage Temperature	T_{stg}		-65 to + 190	$^\circ\text{C}$
Maximum Internal Thermal Resistance Junction-to-Case	R_{thJC}	DC operation	1.00	K/W
Thermal Resistance, Case-to-Sink	R_{thCS}	Mounting surface flat, smooth and greased	0.25	K/W
Mounting Torque	T	Non-lubricated threads	2.3 – 3.4 (20 – 30)	$\text{m}\bullet\text{N}$ ($\text{in}\bullet\text{lb}$)
Approximate Weight	wt		17 (0.8)	g (oz)

